

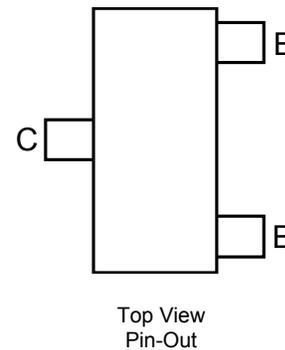
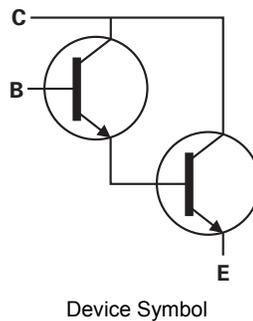
**80V NPN DARLINGTON TRANSISTOR IN SOT23**

**Features**

- $BV_{CES} > 80V$
- Epitaxial Planar Die Construction
- Ideal for Low Power Amplification and Switching
- High Current Gain
- **Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **Qualified to AEC-Q101 Standards for High Reliability**

**Mechanical Data**

- Case: SOT23
- Case Material: molded plastic, "Green" molding compound
- UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish – Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 
- Weight 0.008 grams (approximate)

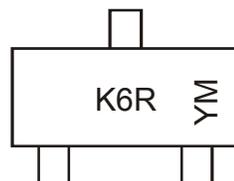


**Ordering Information** (Note 4)

Part Number	Compliance	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
MMBTA28-7-F	AEC-Q101	K6R	7	8	3,000
MMBTA28-13-F	AEC-Q101	K6R	13	8	10,000

- Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
  2. See [http://www.diodes.com/quality/lead\\_free.html](http://www.diodes.com/quality/lead_free.html) for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
  3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
  4. For packaging details, go to our website at <http://www.diodes.com/products/packages.html>.

**Marking Information**



K6R = Product Type Marking Code  
 YM = Date Code Marking  
 Y or  $\bar{Y}$  = Year (ex: B = 2014)  
 M or  $\bar{M}$  = Month (ex: 9 = September)

Date Code Key

Year	2010	2011	2012	2013	2014	2015	2016	2017
Code	X	Y	Z	A	B	C	D	E

Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	O	N	D

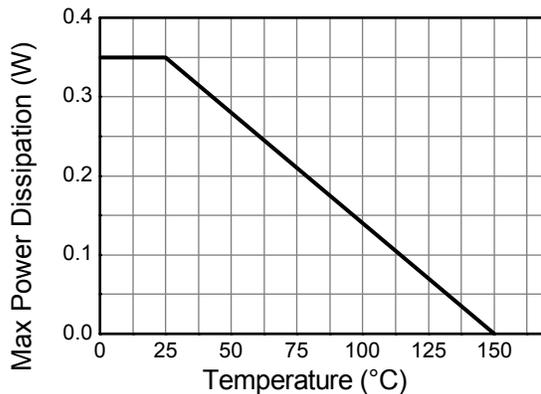
**Absolute Maximum Ratings** (@ $T_A = +25^\circ\text{C}$ , unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	$V_{CBO}$	80	V
Collector-Emitter Voltage	$V_{CES}$	80	V
Emitter-Base Voltage	$V_{EBO}$	12	V
Continuous Collector Current	$I_C$	500	mA

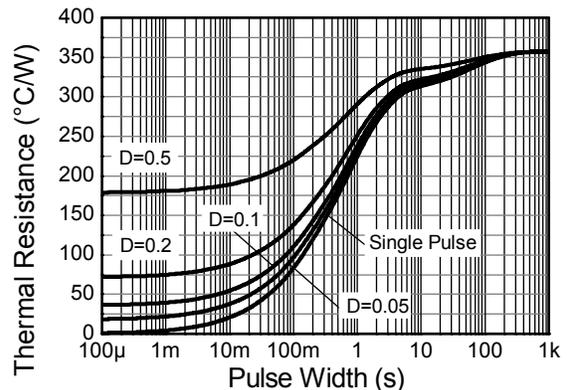
**Thermal Characteristics** (@ $T_A = +25^\circ\text{C}$ , unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation	$P_D$	310	mW
		350	
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	403	$^\circ\text{C/W}$
		357	
Thermal Resistance, Junction to Leads	$R_{\theta JL}$	350	$^\circ\text{C/W}$
Operating and Storage Temperature Range	$T_J, T_{STG}$	-55 to +150	$^\circ\text{C}$

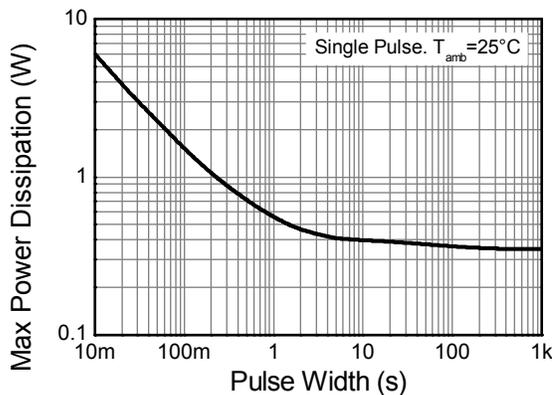
- Notes:
- For a device mounted on minimum recommended pad layout 1oz copper that is on a single-sided FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.
  - Same as note (5), except the device is mounted on 15 mm x 15mm 1oz copper.
  - Thermal resistance from junction to solder-point (at the end of the leads).



**Derating Curve**



**Transient Thermal Impedance**



**Pulse Power Dissipation**

**Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
<b>OFF CHARACTERISTICS</b>						
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	80	—	—	V	I <sub>C</sub> = 100μA, I <sub>E</sub> = 0
Collector-Emitter Breakdown Voltage (Note 8)	BV <sub>CES</sub>	80	—	—	V	I <sub>C</sub> = 100μA, V <sub>BE</sub> = 0
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	12	—	—	V	I <sub>E</sub> = 100μA, I <sub>C</sub> = 0
Collector cut-off current	I <sub>CBO</sub>	—	—	100	nA	V <sub>CB</sub> = 60V, I <sub>E</sub> = 0
	I <sub>CES</sub>	—	—	500	nA	V <sub>CE</sub> = 60V, V <sub>BE</sub> = 0
Emitter-base Cut-off Current	I <sub>EBO</sub>	—	—	100	nA	V <sub>EB</sub> = 10V, I <sub>C</sub> = 0
<b>ON CHARACTERISTICS (Note 8)</b>						
Static Forward Current Transfer Ratio	h <sub>FE</sub>	10,000 10,000	—	—	—	I <sub>C</sub> = 10mA, V <sub>CE</sub> = 5V I <sub>C</sub> = 100mA, V <sub>CE</sub> = 5V
Collector-Emitter Saturation Voltage	V <sub>CE(sat)</sub>	—	—	1.2 1.5	V	I <sub>C</sub> = 10mA, I <sub>B</sub> = 10μA I <sub>C</sub> = 100mA, I <sub>B</sub> = 100μA
Base-Emitter Turn-On Voltage	V <sub>BE(on)</sub>	—	—	2.0	V	I <sub>C</sub> = 100mA, V <sub>CE</sub> = 5V
<b>SMALL SIGNAL CHARACTERISTICS (Note 8)</b>						
Current Gain-Bandwidth Product	f <sub>T</sub>	125	—	—	MHz	I <sub>C</sub> = 10mA, V <sub>CE</sub> = 5V, f = 100MHz
Output Capacitance	C <sub>obo</sub>	—	8.0	—	pF	V <sub>CB</sub> = 10V, f = 1MHz, I <sub>E</sub> = 0
Input Capacitance	C <sub>ibo</sub>	—	15.0	—	pF	V <sub>EB</sub> = 0.5V, f = 1MHz, I <sub>C</sub> = 0

Note: 8. Measured under pulsed conditions. Pulse width ≤ 300μs. Duty cycle ≤ 2%

**Typical Electrical Characteristics** (@ $T_A = +25^\circ\text{C}$ , unless otherwise specified.)

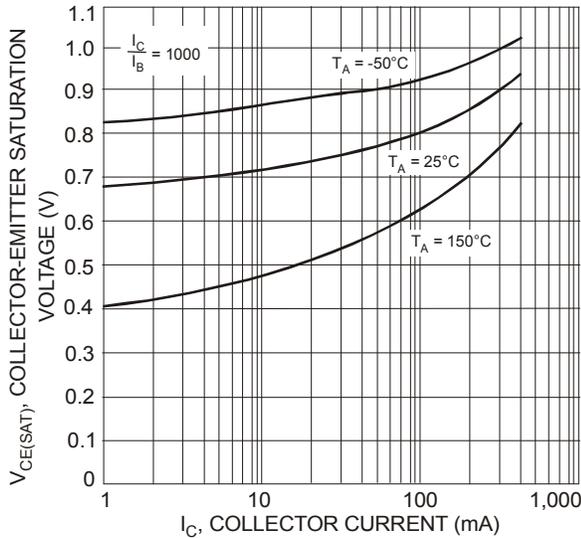


Fig. 2 Typical Collector-Emitter Saturation Voltage vs. Collector Current

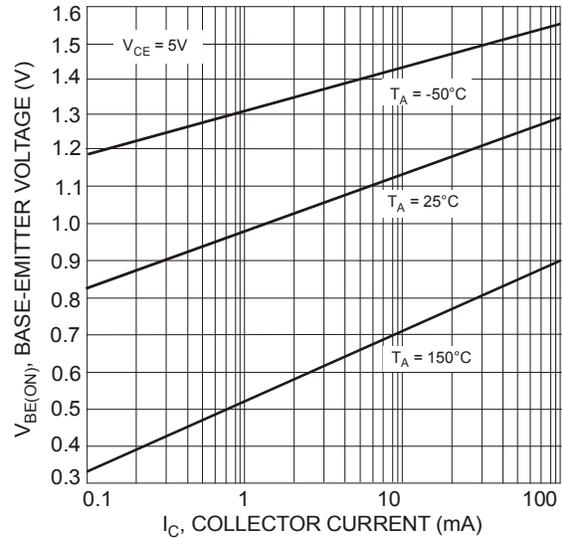


Fig. 3 Typical Base-Emitter Voltage vs. Collector Current

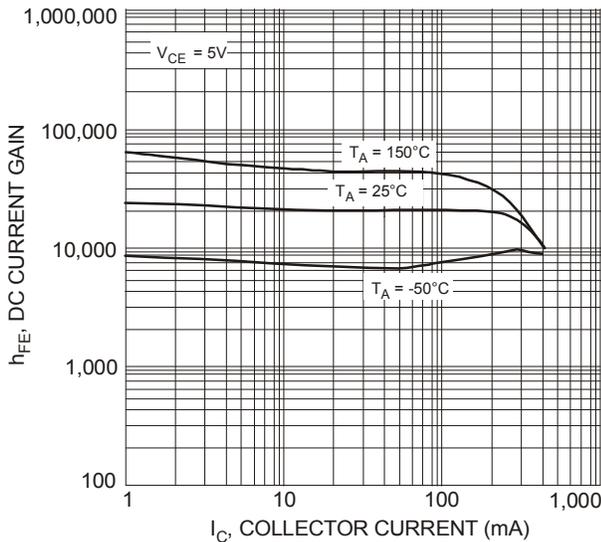


Fig. 4 Typical DC Current Gain vs. Collector Current

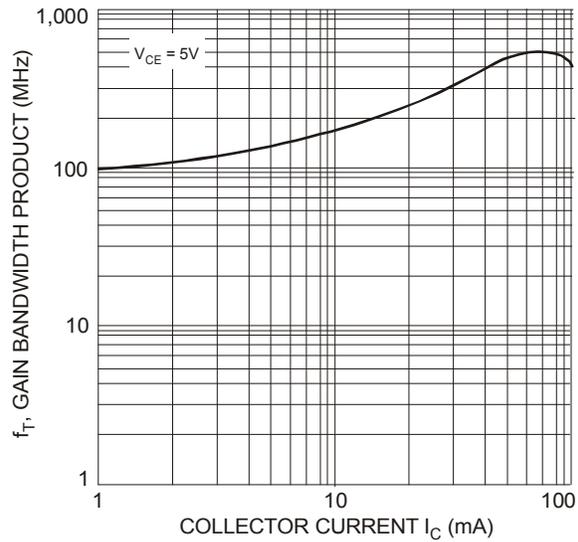
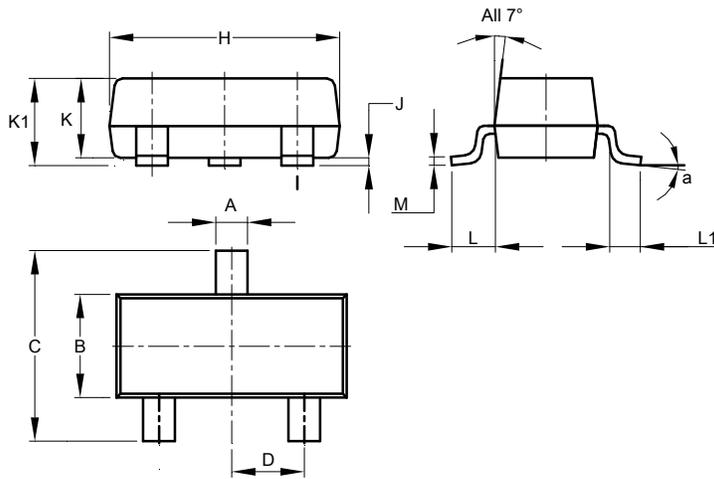


Fig. 5 Typical Gain Bandwidth Product vs. Collector Current

**Package Outline Dimensions**

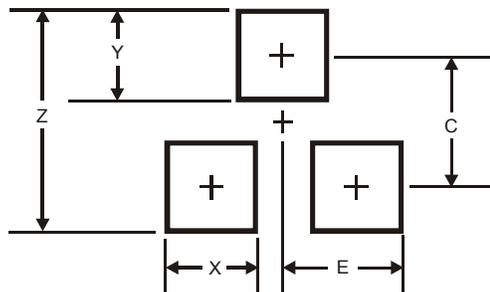
Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for latest version.



SOT23			
Dim	Min	Max	Typ
A	0.37	0.51	0.40
B	1.20	1.40	1.30
C	2.30	2.50	2.40
D	0.89	1.03	0.915
F	0.45	0.60	0.535
G	1.78	2.05	1.83
H	2.80	3.00	2.90
J	0.013	0.10	0.05
K	0.890	1.00	0.975
K1	0.903	1.10	1.025
L	0.45	0.61	0.55
L1	0.25	0.55	0.40
M	0.085	0.150	0.110
a	8°		
All Dimensions in mm			

**Suggested Pad Layout**

Please see AP02001 at <http://www.diodes.com/datasheets/ap02001.pdf> for the latest version.



Dimensions	Value (in mm)
Z	2.9
X	0.8
Y	0.9
C	2.0
E	1.35

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